- 1. (Griffiths ed.5, 4.16) Suppose the field inside a large piece of dielectric is  $E_0$ , so that the electric displacement is  $D_0 = \epsilon_0 E_0 + P$ .
  - (a) Now a small spherical cavity (see Fig. 4.19 in the text) is hollowed out of the material. Find the field at the center of the cavity in terms of  $E_0$  and P, and find the displacement at the center of the cavity in terms of  $D_0$  and P. Here and in the rest of this problem assume that the polarization is "frozen in," so it doesn't change when the cavity is excavated.
  - (b) Do the same for a long needle-shaped cavity running parallel to P. (Again, see Fig. 4.19). *Hint*: ignore any asymmetry at the top and the bottom of the needle, which the text picture indicates. Note that "long" means that if L is the length of the needle and A is its cross-sectional area, we have  $A/L^2$  sufficiently small such that  $|P|A/(4\pi\epsilon_0(L/2)^2) \ll |E_0|$ .
  - (c) Do the same for a thin wafer-shaped cavity perpendicular to P.(Again, see Fig. 4.19). Assume the cavities are small enough that P,  $E_0$ , and  $D_0$  are essentially uniform. *Hint*: carving out a cavity is the same as superimposing an object of the same shape but opposite polarization.
- 1. We learn from example 4.2 that the electric field inside sphere due to uniform polarization is

$$E' = -\frac{1}{3\varepsilon_0} P. \tag{1}$$

So the electric field at center due to spherical cavity is

$$\begin{split} & \boldsymbol{E} = \boldsymbol{E_0} + \frac{1}{3\varepsilon_0} \boldsymbol{P}, \\ \Rightarrow & \boldsymbol{D} = \varepsilon_0 \bigg( \boldsymbol{E_0} + \frac{1}{3\varepsilon_0} \boldsymbol{P} \bigg) = \boldsymbol{D_0} - \frac{2}{3} \boldsymbol{P} \end{split} \tag{2}$$

1. As hinted,  $|{m P}|A/\Big(4\pi \varepsilon_0 \Big(\frac{L}{2}\Big)^2\Big) \ll |{m E_0}|$  implies that at the center of cavity,

$$E \approx E_0$$

$$\Rightarrow D = \varepsilon_0 E_0 = D_0 - P$$
(3)

3. We can treat the cavity as a parallel plate capacitor. Its surface charge density is

$$\sigma = \frac{q}{A} = P. \tag{4}$$

So the electric field at center of cavity due to wafer is  $m{E}' = -rac{m{P}}{arepsilon_0}$  , and thus

$$E = E_0 + \frac{P}{\varepsilon_0},$$

$$D = \varepsilon_0 E = D_0$$
(5)

2. A long cylindrical coaxial capacitor consists of an inner conductor of radius a and an outer conductor of radius b. The region between the conductors is filled with a linear and isotropic but inhomogeneous dielectric with relative permittivity given by  $\epsilon_r(s) = \alpha s^{-2}$ , in which s is the usual cylindrical radial coordinate. The capacitor is charged to a voltage V.

Determine the electric field between the conductors as a function of the voltage V and the capacitor geometry for these conditions.

For a dialectic, the absence of free charge gives  $\rho_f=0.$  So Gauss law becomes:

$$\nabla \cdot \vec{D} = \rho_f = 0$$
 
$$\frac{1}{s} \partial_s (s D_s) = 0$$
 
$$D_s = \frac{C}{s},$$
 (6)

for some constant C. Noticing  $\vec{D}(s)=arepsilon_0arepsilon_r\vec{E}=arepsilon_0\alpha s^{-2}\vec{E},$  we have

$$\begin{split} \vec{E} &= \frac{Cs}{\varepsilon \alpha} \hat{s}, \\ V &= -\int_{a}^{b} \vec{E} \cdot d\vec{l} = -\frac{C}{\varepsilon_{0} \alpha} \int_{a}^{b} s \, ds = -\frac{C}{2\varepsilon_{0} \alpha} (b^{2} - a^{2}). \end{split} \tag{7}$$

We find C to be

$$C = \frac{-2\varepsilon\alpha V}{b^2 - a^2}. (8)$$

And thus

$$\vec{E}(s) = \frac{-2\varepsilon\alpha V s}{\varepsilon\alpha(b^2 - a^2)} = \boxed{\frac{2V s}{a^2 - b^2}\hat{s}.} \tag{9}$$

3. (Griffiths ed.5, 4.25) Suppose the entire region below z=0 is filled with a uniform linear dielectric material of susceptibility  $\chi_e$  and the region above z=0 is filled with a uniform linear dielectric material with a different susceptibility  $\chi'_e$  A point charge q is at the location (x=0,y=0,z=d), where d>0 (see Fig. 4.28 in the text). Find the potential in both regions (z>0 and z<0).

$$\begin{split} V^{>}(r,z) &= \frac{1}{4\pi\varepsilon'} \left( \frac{q}{\left(r^2 + (z-d)^2\right)^{1/2}} + \frac{q'}{\left(r^2 + (z+d)^2\right)^{1/2}} \right) \\ \Rightarrow V^{>}(r,0) &= \frac{1}{4\pi\varepsilon'} \frac{q + q'}{\left(r^2 + d^2\right)^{1/2}}, \quad \frac{\partial V^{>}}{\partial z}(r,0) = \frac{1}{4\pi\varepsilon'} \frac{d(q-q')}{\left(r^2 + d^2\right)^{3/2}}. \end{split} \tag{10}$$

and,

$$\begin{split} V^{<}(r,z) &= \frac{1}{4}\pi\varepsilon \frac{q''}{\left(r^2 + (z-d)^2\right)^{1/2}} \\ \Rightarrow V^{<}(r,0) &= \frac{1}{4\pi\varepsilon} \frac{q''}{\left(r^2 + d^2\right)^{1/2}}, \quad \frac{\partial V^{<}}{\partial z}(r,0) = \frac{1}{4\pi\varepsilon} \frac{q''}{\left(r^2 + d^2\right)^{3/2}}, \end{split} \tag{11}$$

where  $\varepsilon' = \varepsilon_0 (1 + \chi_e'), \varepsilon = \varepsilon_0 (1 + \chi_e).$ 

Boundary condition gives

$$\begin{split} &\frac{1}{\varepsilon'}(q+q') = \frac{q''}{\varepsilon}, \quad (q-q') = q'' \\ &\Rightarrow q'' = \frac{2\varepsilon}{\varepsilon + \varepsilon'}q, \quad q' = \frac{\varepsilon' - \varepsilon}{\varepsilon' + \varepsilon}q \end{split} \tag{12}$$

Hence,

$$V^{>}(r,z) = \frac{q}{4\pi\varepsilon'} \left( \frac{1}{(r^2 + (z-d)^2)^{\frac{1}{2}}} + \left( \frac{\varepsilon' - \varepsilon}{\varepsilon' + \varepsilon} \right) \frac{1}{(r^2 + (z+d)^2)^{\frac{1}{2}}} \right), \quad (z \ge 0);$$

$$V^{<}(r,z) = \frac{2q}{4\pi(\varepsilon' + \varepsilon)} \frac{1}{(r^2 + (z+d)^2)^{\frac{1}{2}}}, \quad (z \le 0.)$$
(13)

- 4. A ideal dipole  $p = p\hat{z}$  is in the center of a spherical uniform dielectric shell with inner radius a and outer radius b. Find the potential in all regions.
- Inside the cavity, (r < a): Separation of Variables with dipole gives

$$V_I(r,\theta) = \frac{1}{4\pi\varepsilon_0} \left( \frac{p\cos\theta}{r^2} + \sum_{l=0}^{\infty} A_{1,l} r^l P_l(\cos\theta) \right)$$
 (14)

where p is the dipole moment. Dipole expansion gives

$$V_I(r,\theta) = \frac{p}{4\pi\varepsilon_0} \left( \frac{1}{r^2} + \frac{r}{a^3} \left( \frac{1}{\varepsilon_r} (A_2 + B_2) - 1 \right) \right) \cos\theta \tag{15}$$

$$\frac{\partial V_I}{\partial r} = \frac{p\cos\theta}{4\pi\varepsilon 0a^3} \left( \frac{1}{\varepsilon_r} (A_2 + B_2) - 3 \right) \tag{16}$$

• Within shell, (a < r < b), assuming a dialectic constant  $\varepsilon_r$ , we can jot down the following by using results from Separation of Variables:

$$V_{\rm II}(r,\theta) = \frac{1}{4\pi\varepsilon} \sum_{l=0}^{\infty} \left( A_{2,l} r^l + \frac{B_{2,l}}{r^{l+1}} \right) P_l(\cos\theta)$$
 (17)

Dipole expansion, taking l = 1 gives:

$$V_{\rm II}(r,\theta) = \frac{p}{4\pi\varepsilon} \left( A_2 \frac{r}{a^3} + \frac{B_2}{r^2} \right) \cos\theta. \tag{18}$$

$$\frac{\partial V_{\mathrm{II}}(a,\theta)}{\partial r} = \frac{p\cos\theta}{4\pi\varepsilon a^3}(A_2 - 2B_2); \quad \frac{\partial V_{\mathrm{II}}(b,\theta)}{\partial r} = \frac{p}{4\pi\varepsilon b^3} \left(A_2 \left(\frac{b}{a}\right)^3 - 2B_2\right) \tag{19}$$

• Outside the shell, (r > b):

$$V_{\text{III}}(r,\theta) = \frac{1}{4\pi\varepsilon_0} \sum_{l=0}^{\infty} \frac{B_{3,l}}{r^{l+1}} P_l(\cos\theta). \tag{20}$$

Taking l = 1 gives:

$$V_{\rm III}(r,\theta) = \frac{p}{4\pi\varepsilon r^2} \left( A_2 \left(\frac{b}{a}\right)^3 + B_2 \right). \tag{21}$$

$$\frac{\partial V_{\rm III}(b,\theta)}{\partial r} = \frac{p}{4\pi\varepsilon b^3}(-2)\left(A_2\left(\frac{b}{a}\right)^3 + B_2\right) \eqno(22)$$

**Boundary Conditions:** 

$$\varepsilon \frac{\partial V_{\rm II}(a,\theta)}{\partial r} = \varepsilon_0 \frac{\partial V_I(a,\theta)}{\partial r}, 
\varepsilon_0 \frac{\partial V_{\rm III}(b,\theta)}{\partial r} = \varepsilon \frac{\partial V_{\rm II}}{\partial r}(b,\theta)$$
(23)

Painful algebra gives:

$$\begin{split} A_2 &= \left(\frac{b}{a}\right)^{-3} \frac{B_2(2\varepsilon_r - 2)}{2 + \varepsilon_r}, \\ B_2 &= \frac{3\varepsilon_r}{(1 + 2\varepsilon_r) - 2\left(\frac{a}{b}\right)^3 \frac{\left(1 - \varepsilon_r\right)^2}{2 + \varepsilon}} \equiv f(\varepsilon_r, a, b) \end{split} \tag{24}$$

We thus conclude:

$$\begin{split} V_{I}(r,\theta) &= \frac{p\cos\theta}{4\pi\varepsilon r^{2}} \Bigg(1 + \left(\frac{r}{a}\right)^{3} \bigg(\frac{f(\varepsilon_{r},a,b)}{\varepsilon_{r}}\bigg) \Bigg(1 + \left(\frac{a}{b}\right)^{3} \frac{2(\varepsilon_{r}-1)}{2+\varepsilon_{r}}\bigg) - 1\Bigg), \\ V_{\text{II}}(r,\theta) &= \frac{p\cos\theta}{4\pi\varepsilon r^{2}} f(\varepsilon_{r},a,b) \Bigg(1 + \frac{2(\varepsilon_{r}-1)}{2+\varepsilon_{r}} \bigg(\frac{r}{b}\bigg)^{3}\Bigg), \end{split} \tag{25}$$
 
$$V_{\text{III}}(r,\theta) &= \frac{p\cos\theta}{4\pi\varepsilon r^{2}} \frac{3f(\varepsilon_{r},a,b)}{(\varepsilon_{r}+2)} \end{split}$$

5. (Griffiths ed.5, 4.26) A spherical conductor of radius a carries a charge Q. It is surrounded by linear (isotropic, homogenous) dielectric material of electric susceptibility  $\chi_e$ , out to radius b. (See Fig. 4.32 in the text.) Find the energy of this configuration.

Identical set up, with dielectric material of permittivity  $\varepsilon$ , can be found in Example 4.5 of textbook. Citing the result, we have:

$$\mathbf{D} = \begin{cases} \frac{Q}{4\pi r^2} \hat{r} & (r > a) \\ 0 & (r < a) \end{cases}, \quad \mathbf{E} = \begin{cases} 0 & (r < a) \\ \frac{Q}{4\pi \varepsilon r^2} \hat{r} & (r \in a, b) \\ \frac{Q}{4\pi \varepsilon_0 r^2} \hat{r} & (r > b) \end{cases}$$
(26)

Using  $W=\frac{1}{2}\int_V {m D}\cdot {m E}\, {\rm d} au,$  with  $\varepsilon=\varepsilon_0(1+\chi_e),$  we have:

$$W = \frac{1}{2} \int \mathbf{D} \cdot \mathbf{E} \, d\tau$$

$$= \frac{Q^2}{8\pi} \left( \frac{1}{\varepsilon} \int_a^b \frac{1}{r^2} \frac{1}{r^2} r^2 \, dr + \frac{1}{\varepsilon_0} \int_b^\infty \frac{1}{r^2} \, dr \right)$$

$$= \frac{Q^2}{8\pi\varepsilon_0} \left( \left( \frac{1}{a} - \frac{1}{b} \right) \left( \frac{1}{1 + \chi_e} \right) + \frac{1}{b} \right)$$

$$= \left( \frac{1}{a} + \frac{\chi_e}{b} \right) \frac{Q^2}{8\pi\varepsilon_0 (1 + \chi_e)}$$

$$(27)$$